

TECHNICAL DATA DATA SHEET 370, REV. A

# HERMETIC POWER MOSFET N-CHANNEL

DESCRIPTION: 100 VOLT, 33 AMP, 0.06 OHM MOSFET IN A HERMETIC TO-257 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE AT  $T_{\Delta}$  = 25°C UNLESS OTHERWISE SPECIFIED.

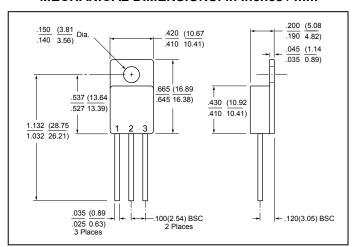
RATING	SYMBÔL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	$V_{GS}$	-	-	±20	Volts
CONTINUOUS DRAIN CURRENT V <sub>GS</sub> =10V, T <sub>C</sub> = 25°C	I <sub>D</sub>	-	-	33	Amps
$V_{GS}=10V, T_{C}=100^{\circ}C$				20	
PULSED DRAIN CURRENT @ T <sub>C</sub> = 25°C	I <sub>DM</sub>	-	-	99	Amps(pk)
OPERATING AND STORAGE TEMPERATURE	$T_{OP}/T_{STG}$	-55	-	+150	°C
TERMAL RESISTANCE JUNCTION TO CASE	$R_{ heta JC}$	-	-	0.80	°C/W
TOTAL DEVICE DISSIPATION @ T <sub>C</sub> = 25°C	$P_D$	-	-	150	Watts

## **ELECTRICAL CHARACTERISTICS**

DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV <sub>DSS</sub>	100	-	-	Volts
$V_{GS} = 0V, I_D = 250\mu$	A				
DRAIN TO SOURCE ON STATE RESISTANCE					
$I_D = 16.5A, V_{GS} = 10V@T_J = 25^\circ$	$C \mid R_{DS(ON)}$	-	-	0.06	Ω
FORWARD TRANSCONDUCTANCE	$g_{fs}$	8.0	-	-	S(1/Ω)
$V_{DS} = 80 \text{Vdc}, I_{DS} = 16.5$	A				
ZERO GATE VOLTAGE DRAIN CURRENT		-	-		μΑ
$V_{DS} = 100 \text{Vdc}, V_{GS} = 0 \text{Vd}$	Ic I <sub>DSS</sub>			10	
$V_{DS} = 100Vdc$				100	
$V_{GS} = 0 Vdc, T_J = 125^{\circ}C$					
GATE TO BODY LEAKAGE CURRENT $V_{GS} = \pm 20V_{GS}$	c, I <sub>GSS</sub>	-	-	+100	nA
$V_{DS} = 0Vdc$				-100	
TOTAL GATE CHARGE $(V_{GS} = 10 \text{ Vd})$			52	110	nC
GATE TO SOURCE CHARGE $V_{DS} = 80Vdc$	. 90		12		
GATE TO DRAIN CHARGE $I_D = 33Ad$			32		
TURN ON DELAY TIME $(V_{DD} = 50)$	-()	-	18	40	nsec
RISE TIME $I_D = 33Ad$			164	330	
TURN OFF DELAY TIME $V_{GS} = 10 \text{ Vd}$	- ( - ,		48	100	
FALL TIME $R_G = 9.10$	<i>'</i>		83	170	
FORWARD VOLTAGE, $(I_S = 33Adc, V_{GS} = 0V)$	,	-	1.0	2.0	Volts
$(I_S = 33Adc, V_{GS} = 0Vdc, T_J = 125^{\circ}C)$			0.98		
REVERSE RECOVERY TIME $(I_S = 33Adc, V_{GS} = 0Vc)$		-	-	144	nsec
REVERSE RECOVERY CHARGE di/dt = 100A/μsec				.93	μС
INPUT CAPACITANCE $(V_{DS} = 25 \text{ Vd})$		-	1830	2500	pF
OUTPUT CAPACITANCE $V_{GS} = 0 \text{ Vd}$			678	1200	
REVERSE TRANSFER CAPACITANCE f = 1 MH.	z) C <sub>rss</sub>		559	1100	

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#### **MECHANICAL DIMENSIONS: in Inches / mm**



TO-257

## **PINOUT TABLE**

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET IN A TO-257 PACKAGE			
STANDARD VERSION	DRAIN	SOURCE	GATE
'R' VERSION	GATE	DRAIN	SOURCE

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